

10Gb/s XFP DWDM 120km Transceiver HXXD-ALxxX1x

Features

- Up to 11.3Gb/s data links
- DWDM EML transmitter and APD receiver
- 100 GHz ITU channel spacing with integrated wavelength locker
- Up to 120km on 9/125μm SMF
- Hot-pluggable XFP footprint
- Duplex LC/UPC type pluggable optical interface
- RoHS-10 compliant and lead-free
- Support Digital Monitoring interface
- Single +3.3V power supply
- Maximum power consumption 1.8W
- Metal enclosure, for lower EMI
- Meet ESD requirements, resist 8KV direct contact voltage
- Case operating temperature
Commercial: 0 ~ +70°C
Extended: -10 ~ +80°C
Industrial: -40 ~ +85°C



Applications

- 10GBASE-ZR/ZW & 10G Ethernet
- SONET OC-192 & SDH STM I-64.1
- 10G Fiber Channel

Part Number Ordering Information

Part Number	Data Rate (Gb/s)	Wavelength (nm)	Transmission Distance(km)	Temperature (°C) (Operating Case)
HXXD-ALxxX1C	10.3125	Refer to wavelength selection	120	0~70 commercial
HXXD-ALxxX1E	10.3125		120	-10~80 extended
HXXD-ALxxX1I	10.3125		120	-40~85 Industrial

Wavelength Selection: C-band λ_c Wavelength Guide Pin Descriptions

Channel (xx)	Wavelength (nm)	Frequency (THZ)	Channel (xx)	Wavelength (nm)	Frequency (THZ)
17	1563.86	191.70	39	1546.12	193.90
18	1563.05	191.80	40	1545.32	194.00
19	1562.23	191.90	41	1544.53	194.10
20	1561.42	192.00	42	1543.73	194.20
21	1560.61	192.10	43	1542.94	194.30
22	1559.79	192.20	44	1542.14	194.40
23	1558.98	192.30	45	1541.35	194.50
24	1558.17	192.40	46	1540.56	194.60
25	1557.36	192.50	47	1539.77	194.70
26	1556.55	192.60	48	1538.98	194.80
27	1555.75	192.70	49	1538.19	194.90
28	1554.94	192.80	50	1537.40	195.00
29	1554.13	192.90	51	1536.61	195.10
30	1553.33	193.00	52	1535.82	195.20
31	1552.52	193.10	53	1535.04	195.30
32	1551.72	193.20	54	1534.25	195.40
33	1550.92	193.30	55	1533.47	195.50
34	1550.12	193.40	56	1532.68	195.60
35	1549.32	193.50	57	1531.90	195.70
36	1548.51	193.60	58	1531.12	195.80
37	1547.72	193.70	59	1530.33	195.90
38	1546.92	193.80	60	1529.55	196.00
Non-ITU	Peak wavelength between 1528.77nm-1563.86		61	1528.77	196.10

I. Absolute Maximum Ratings

It has to be noted that the operation in excess of any individual absolute maximum ratings might cause permanent damage to this module.

Parameter	Symbol	Min	Max	Unit	Notes
Storage Temperature	T _S	-40	85	°C	
Power Supply Voltage	V _{CC}	-0.5	3.6	V	
Relative Humidity (non-condensation)	RH	5	95	%	
Damage Threshold	TH _d	0		dBm	

II. Recommended Operating Conditions

Parameter	Symbol	Min	Typical	Max	Unit	Notes
Operating Case Temperature	T _{OP}	0		70	°C	commercial
		-10		80		extended
		-40		85		Industrial
Power Supply Voltage	V _{CC}	3.135	3.3	3.465	V	
Data Rate			10.3125		Gb/s	
Control Input Voltage High		2		V _{CC}	V	
Control Input Voltage Low		0		0.8	V	
Link Distance (SMF)	D			120	km	9/125um

III. General Description

Walsun'HXXD-ALxxX1x XFP transceiver is designed for use in 10-Gigabit Ethernet links up to 120km over single mode fiber. The module consists of DWDM EML Laser, APD and Preamplifier in a high-integrated optical sub-assembly. Digital diagnostics functions are available via a 2-wire serial interface, as specified in XFP MSA. This module is designed for single mode fiber and operates at a nominal wavelength of 100GHz ITU Grid, C Band DWDM wavelength.

HXXD-ALxxX1x transceivers provide a unique enhanced digital diagnostic monitoring interface, which allows real-time access to device operating parameters such as transceiver temperature, laser bias current, transmitted optical power, and received optical power and transceiver supply voltage. It also defines a sophisticated system of alarm and warning flags, which alerts end-users when particular operating parameters are outside of a factory set normal range.

The XFP MSA defines a 256-byte memory map in EEPROM that is accessible over a 2-wire serial

interface at the 8bit address 1010000X (A0h). The digital diagnostic monitoring interface makes use of the 8bit address 1010001X (A2h), so the originally defined serial ID memory map remains unchanged.

IV. Pin Assignment and Pin Description

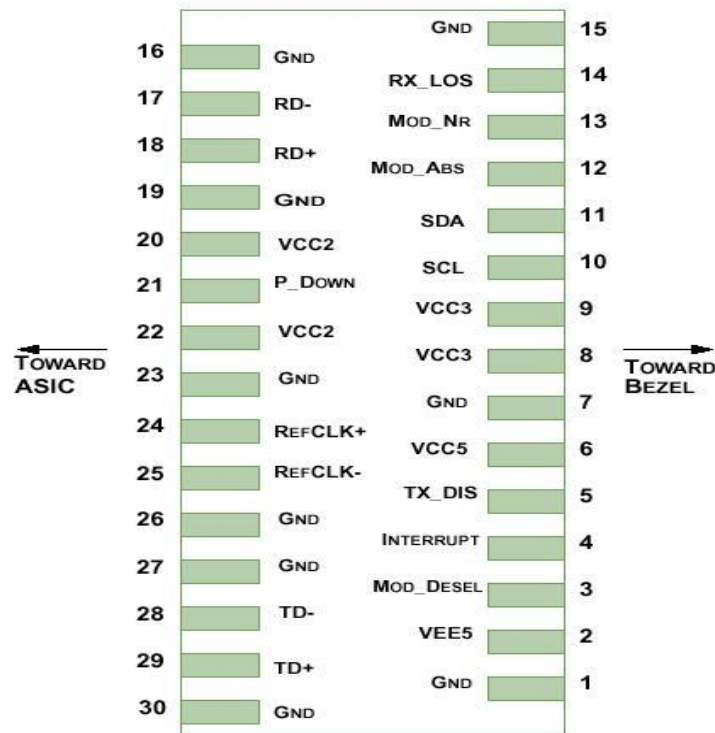


Figure1. Diagram of host board connector block pin numbers and names

Pin	Symbol	Name/Description	Notes
1	GND	Module Ground	1
2	VEE5	Optional -5.2 Power Supply – Not required	
3	Mod-Desel	Module De-select; When held low allows the module to respond to 2-wire serial interface commands	
4	Interrupt	Interrupt (bar); Indicates presence of an important condition which can be read over the serial 2-wire interface	2
5	TX_DIS	Transmitter Disable; Transmitter laser source turned off	
6	VCC5	+5 Power Supply – Not required	
7	GND	Module Ground	1
8	VCC3	+3.3V Power Supply	
9	VCC3	+3.3V Power Supply	

10	SCL	Serial 2-wire interface clock	
11	SDA	Serial 2-wire interface data line	2
12	Mod_Abs	Module Absent; Indicates module is not present. Grounded in the module.	2
13	Mod_NR	Module Not Ready; Walsun's defines it as a logical OR between RX_LOS and Loss of Lock in TX/RX.	2
14	RX_LOS	Receiver Loss of Signal indicator	2
15	GND	Module Ground	1
16	GND	Module Ground	1
17	RD-	Receiver inverted data output	
18	RD+	Receiver non-inverted data output	
19	GND	Module Ground	1
20	VCC2	+1.8V Power Supply – Not required	
21	P_Down/RST	Power Down; When high, places the module in the low power stand-by mode and on the falling edge of P_Down initiates a module reset	
		Reset; The falling edge initiates a complete reset of the module including the 2-wire serial interface, equivalent to a power cycle.	
22	VCC2	+1.8V Power Supply – Not required	
23	GND	Module Ground	1
24	RefCLK+	Reference Clock non-inverted input, AC coupled on the host board – Not required	3
25	RefCLK-	Reference Clock inverted input, AC coupled on the host board – Not required	3
26	GND	Module Ground	1
27	GND	Module Ground	1
28	TD-	Transmitter inverted data input	
29	TD+	Transmitter non-inverted data input	
30	GND	Module Ground	1

Notes:

1. Module circuit ground is isolated from module chassis ground within the module.
2. Open collector; should be pulled up with 4.7kΩ-10kΩ on host board to a voltage between 3.15V and 3.6V.
3. A Reference Clock input is not required by the HXXD-ALxxX1x. If present, it will be ignored.

V. Electrical Characteristics

The following electrical characteristics are defined over the Recommended Operating Environment unless otherwise specified.

Parameter	Symbol	Min.	Typ.	Max	Unit	Notes
Power Consumption	p			1.8	W	
Supply Current	Icc			520	mA	
Transmitter						
Single-ended Input Voltage Tolerance	Vcc	-0.3		4.0	V	
AC Common Mode Input Voltage Tolerance (RMS)		15			mV	
Differential Input Voltage Swing	Vin,pp	120		820	mVpp	
Differential Input Impedance	Zin	90	100	110	Ohm	1
Transmit Disable Assert Time				10	us	
Transmit Disable Voltage	Vdis	Vcc-1.3		Vcc	V	
Transmit Enable Voltage	Ven	Vee		Vee +0.8	V	2
Receiver						
Differential Output Voltage Swing	Vout,pp	350		850	mVpp	
Differential Output Impedance	Zout	90	100	110	Ohm	3
Data output rise/fall time	Tr/Tf	28			ps	4
LOS Assert Voltage	VlosH	Vcc-1.3		Vcc	V	5
LOS De-assert Voltage	VlosL	Vee		Vee +0.8	V	5
Power Supply Rejection	PSR	100			mVpp	6

Notes:

1. Connected directly to TX data input pins. AC coupled thereafter.
2. Or open circuit.
3. Input 100 ohms differential termination.
4. These are unfiltered 20-80% values.
5. Loss of Signal is LVTTTL. Logic 0 indicates normal operation; logic 1 indicates no signal detected.
6. Receiver sensitivity is compliant with power supply sinusoidal modulation of 20 Hz to 1.5 MHz up to specified value applied through the recommended power supply filtering network.

VI. Optical Characteristics

The following optical characteristics are defined over the Recommended Operating Environment unless otherwise specified.

Parameter	Symbol	Min.	Typical	Max	Unit	Notes
Transmitter						
Optical Wavelength	λ_c	λ_c -0.1		λ_c +0.1	nm	1
Center Wavelength Spacing			100		GHz	
Optical Spectral Width	$\Delta\lambda$			1	nm	
Side Mode Suppression Ratio	SMSR	30			dB	
Average Optical Power	P _{AVG}	1		6	dBm	2
Optical Extinction Ratio	ER	8.2			dB	
Transmitter and Dispersion Penalty	TDP			3	dB	
Transmitter OFF Output Power	POff			-30	dBm	
Transmitter Eye Mask		Compliant with IEEE802.3ae				
Receiver						
Center Wavelength	λ_C	1270		1610	nm	
Receiver Sensitivity (Average Power)	Sen.			-26	dBm	3
Input Saturation Power (overload)	Psat	-8			dBm	
LOS Assert	LOSA	-35			dB	
LOS De-assert	LOSD			-27	dBm	
LOS Hysteresis	LOSH	0.5			dBm	

Notes:

1. λ_c refer to wavelength selection, and corresponds to approximately 0.8 nm.
2. Class 1 Laser Safety per FDA/CDRH and IEC-825-1 regulations.
3. Measured with Light source 1528.77~1563.86nm, ER=8.2dB; BER≤1E-12 @10.3125Gbps, PRBS=2³¹-1 NRZ.

VII. Digital Diagnostic Functions

The following digital diagnostic characteristics are defined over the Recommended Operating Environment unless otherwise specified.

Parameter	Symbol	Min.	Max	Unit	Notes
Temperature monitor absolute error	DMI_Temp	-3	3	°C	Over operating temp
Supply voltage monitor absolute error	DMI_VCC	-0.15	0.15	V	Full operating range
RX power monitor absolute error	DMI_RX	-3	3	dB	
Bias current monitor	DMI_bias	-10%	10%	mA	
TX power monitor absolute error	DMI_TX	-3	3	dB	

VIII. Mechanical Dimensions

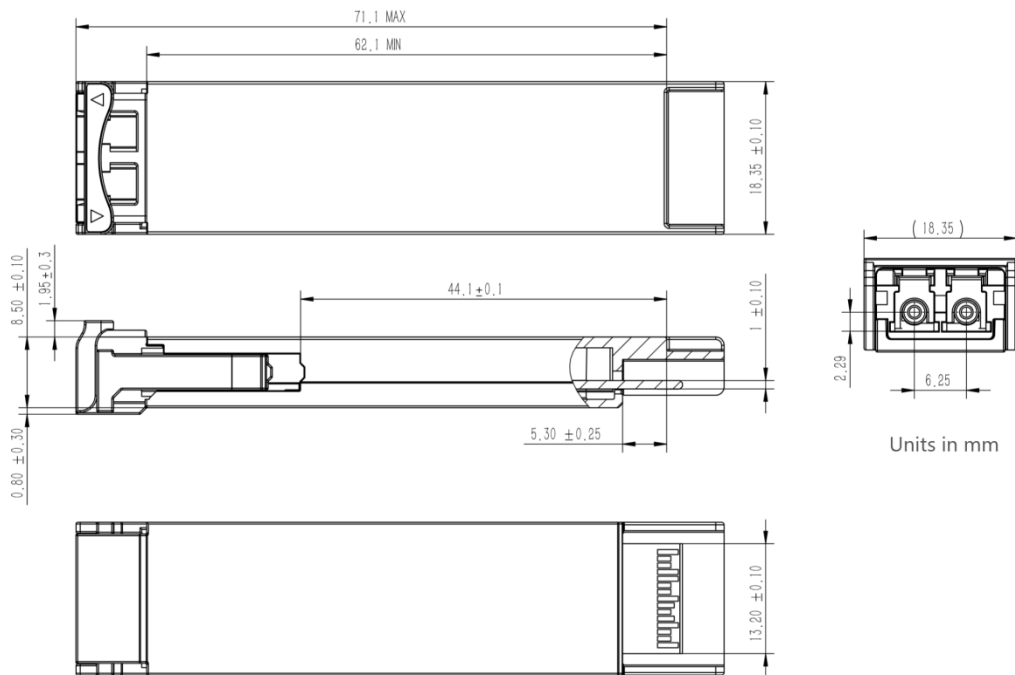


Figure2. Mechanical Outline

IX. Revision History

Version No.	Initiated	Revised contents	Release Date
1.0	Andy Zhang	Preliminary datasheet	2014-06-11
1.1	Andy Zhang	Mechanical Change	2016-04-08

X. Contact us

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